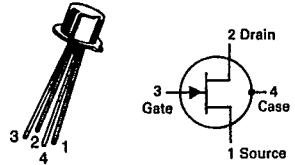


**2N3821  
2N3822  
2N3824**

CASE 20-03, STYLE 1  
TO-72 (TO-206AF)



**JFETs**

**LOW FREQUENCY, LOW NOISE**  
N-CHANNEL — DEPLETION  
JAN, JTX 2N3821 AND JAN, JTX 2N3822  
AVAILABLE

Refer to 2N4220 for graphs.

**MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	50	Vdc
Drain-Gate Voltage	$V_{DG}$	50	Vdc
Gate-Source Voltage	$V_{GS}$	-50	Vdc
Drain Current	$I_D$	10	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.0	mW mW/ $^\circ\text{C}$
Junction Temperature Range	$T_J$	175	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-65 to +200	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)**

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Gate-Source Breakdown Voltage ( $I_G = -1.0 \mu\text{Adc}$ , $V_{DS} = 0$ )	$V_{(BR)GSS}$	-50	—	Vdc
Gate Reverse Current ( $V_{GS} = -30 \text{ Vdc}$ , $V_{DS} = 0$ ) ( $V_{GS} = -30 \text{ Vdc}$ , $V_{DS} = 0$ , $T_A = 150^\circ\text{C}$ )	$I_{GSS}$	— —	-0.1 -100	nAdc
Gate Source Cutoff Voltage ( $I_D = 0.5 \text{ nAdc}$ , $V_{DS} = 15 \text{ Vdc}$ ) 2N3821 2N3822	$V_{GS(\text{off})}$	— —	-4.0 -6.0	Vdc
Gate Source Voltage ( $I_D = 50 \mu\text{Adc}$ , $V_{DS} = 15 \text{ Vdc}$ ) ( $I_D = 200 \mu\text{Adc}$ , $V_{DS} = 15 \text{ Vdc}$ ) 2N3821 2N3822	$V_{GS}$	-0.5 -1.0	-2.0 -4.0	Vdc
Drain Cutoff Current ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = -8.0 \text{ Vdc}$ ) ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = -8.0 \text{ Vdc}$ , $T_A = 150^\circ\text{C}$ ) 2N3824 2N3824	$I_{D(\text{off})}$	— —	0.1 100	nAdc
<b>ON CHARACTERISTICS</b>				
Zero-Gate-Voltage Drain Current(1) ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = 0$ ) 2N3821 2N3822	$I_{DSS}$	0.5 2.0	2.5 10	mAdc
Static Drain-Source On Resistance ( $V_{GS} = 0$ , $I_D = 0$ , $f = 1.0 \text{ kHz}$ ) 2N3824	$r_{DS(\text{on})}$	—	250	Ohms
<b>SMALL-SIGNAL CHARACTERISTICS</b>				
Forward Transfer Admittance ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{ kHz}$ )(1) 2N3821 2N3822	$ Y_{fs} $	1500 3000	4500 6500	$\mu\text{mhos}$
( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = 0$ , $f = 100 \text{ MHz}$ ) 2N3821 2N3822		1500 3000	— —	
Output Admittance(1) ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{ kHz}$ ) 2N3821 2N3822	$ Y_{os} $	— —	10 20	$\mu\text{mhos}$
Input Capacitance ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{iss}$	—	6.0	pF
Reverse Transfer Capacitance ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{ MHz}$ ) 2N3821 2N3822	$C_{rss}$	— —	3.0 3.0	pF
( $V_{GS} = -8.0 \text{ Vdc}$ , $V_{DS} = 0$ , $f = 1.0 \text{ MHz}$ ) 2N3824		—	3.0	

MOTOROLA SMALL-SIGNAL TRANSISTORS, FETs AND DIODES

MOTOROLA SC XSTRS/R F 12E D 6367254 0086614 T

2N3821, 2N3822, 2N3824

T-29-25

ELECTRICAL CHARACTERISTICS (continued) ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
<b>FUNCTIONAL CHARACTERISTICS</b>				
Noise Figure ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = 0$ , $R_S = 1.0 \text{ megohm}$ , $f = 10 \text{ Hz}$ , Noise Bandwidth = 5.0 Hz)	NF	—	5.0	dB
Equivalent Input Noise Voltage ( $V_{DS} = 15 \text{ Vdc}$ , $V_{GS} = 0$ , $f = 10 \text{ Hz}$ , Noise Bandwidth = 5.0 Hz)	$e_n$	—	200	$\text{nv}/\text{Hz}^{1/2}$

(1) Pulse Test: Pulse Width  $\leq 100 \text{ ms}$ , Duty Cycle  $\leq 10\%$ .

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